

Features

- 0.3" (7.62mm) Matrix Height
- Single Digit Display
- Black/Grey Face , White Segment
- IC compatible, Easy assembly
- Dynamic drive connect
- RoHS Compliant, Pb Free

Applications

- Consumer Electronics
- Industrial Equipment

Description

The INND-SS30 series is a 0.3" single digit display. It is a SMD type LED display which can be used in various applications.

Internal Circuit Diagram

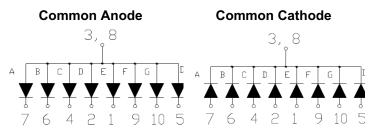
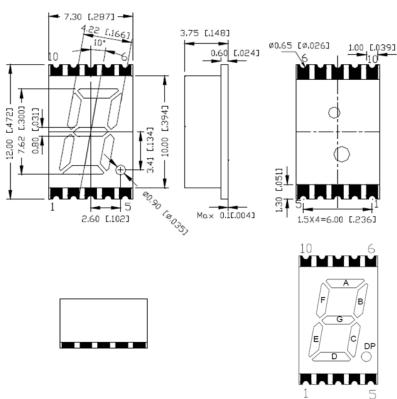


Figure 1. INND-SS30 series Internal Circuit Diagram



Package Dimensions

Figure 2. INND-SS30 series Package Dimensions



Absolute Maximum Rating at 25°C (Note 1)

Product (Per Segment)	Emission Color	Technology	Pd (mW)	IF (mA)	IFP* (mA)	VR (V)	Derate From 25°C (mA/°C)	Top (⁰C)	Тѕт (⁰С)
INND-SS30YGXX	Yellow Green	AlGaInP	70	25	90	5	0.33	-40°C~+105°C	-40°C~+105°C
INND-SS30YXX	Yellow	AlGaInP	70	25	90	5	0.33	-40°C~+105°C	-40°C~+105°C
INND-SS30AXX	Amber	AlGaInP	70	25	90	5	0.33	-40°C~+105°C	-40°C~+105°C
INND-SS30RXX	Red	AlGaInP	70	25	90	5	0.33	-40°C~+105°C	-40°C~+105°C
INND-SS30DRXX	Deep Red	AlGaInP	70	25	90	5	0.33	-40°C~+105°C	-40°C~+105°C
INND-SS30GXX	Green	InGaN	114	30	100	5	0.4	-40°C~+105°C	-40°C~+105°C
INND-SS30BXX	Blue	InGaN	114	30	100	5	0.4	-40°C~+105°C	-40°C~+105°C
INND-SS30WXX	White	InGaN	114	30	100	5	0.4	-40°C~+105°C	-40°C~+105°C

Notes

1. Condition for IFP is pulse of 1/10 duty and 0.1msec width



Electrical Characteristics T_A = 25°C (Note 1)

		VF	(V)@20	mA	λ(nm)@	0)20mA	l*∨(n	ncd)@1	0mA	I _R (µA)@V _R =5V	I _{V-M} @I _F =10mA
Product (Per Segment)	Emission Color	min	typ.	max	λD	λP	min	typ.	max	max	max
INND-SS30YGXX	Yellow Green	-	2.0	2.8	570	572	-	2	-	100	2:1
INND-SS30YXX	Yellow	-	2.0	2.8	590	592	-	8	-	100	2:1
INND-SS30AXX	Amber	-	2.0	2.8	605	612	-	9	-	100	2:1
INND-SS30RXX	Red	-	2.0	2.8	630	644	-	5	-	100	2:1
INND-SS30DRXX	Deep Red	-	2.0	2.8	645	660	-	2	-	100	2:1
INND-SS30GXX	Green	-	3.2	3.8	525	-	-	37	-	100	2:1
INND-SS30BXX	Blue	-	3.2	3.8	465	-	-	7	-	50	2:1
INND-SS30WXX	White	-	3.2	3.8	X: 0.27 Y: 0.25	-	10.7	19.3	-	50	2:1

Notes

1. Performance guaranteed only under conditions listed in above tables.

ESD Precaution

ATTENTION: Electrostatic Discharge (ESD) protection



The symbol above denotes that ESD precaution is needed. ESD protection for GaP and AlGaAs based chips is necessary even though they are relatively safe in the presence of low static-electric discharge. Parts built with AlInGaP, GaN, or/and InGaN based chips are STATIC SENSITIVE devices. ESD precaution must be taken during design and assembly. If manual work or processing is needed, please ensure the device is adequately protected from ESD during the process.

Please be advised that normal static precautions should be taken in the handling and assembly of this device to prevent damage or degradation which may be induced by electrostatic discharge (ESD).





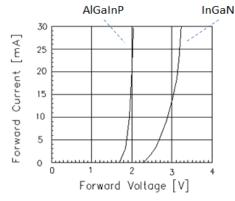


Fig 1. Forward Current vs. Forward Voltage

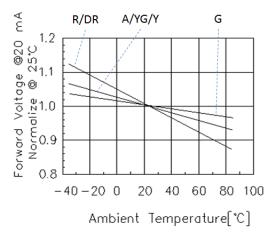
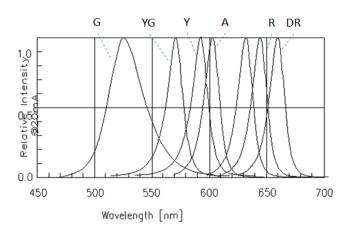
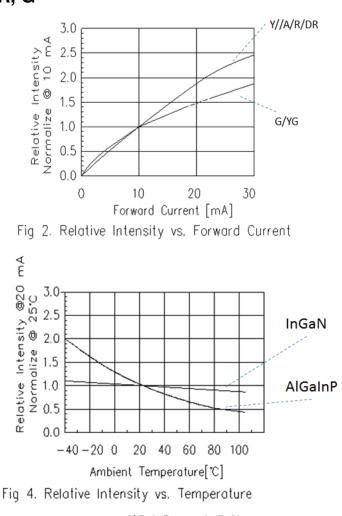
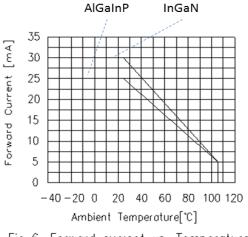


Fig 3. Forward Voltage vs. Temperature











INND-SS30 Series 0.3" SMD Single Digit Display

Characteristic Curves for B

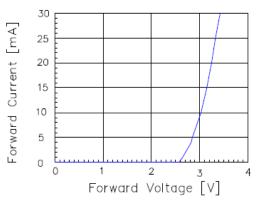
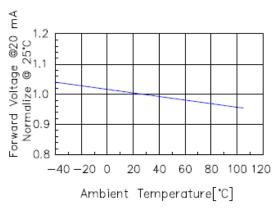
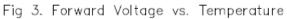


Fig 1. Forward Current vs. Forward Voltage





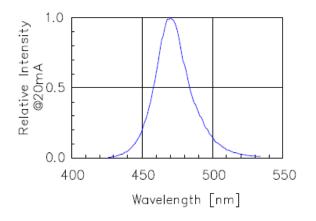
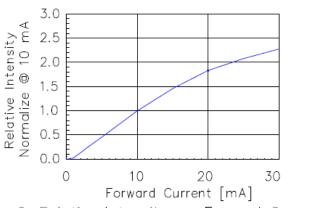


Fig 5. Relative Intensity vs. Wavelength





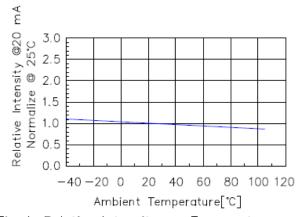
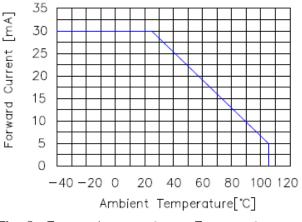
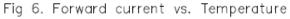


Fig 4. Relative Intensity vs. Temperature







INND-SS30 Series 0.3" SMD Single Digit Display

Characteristic Curves for W

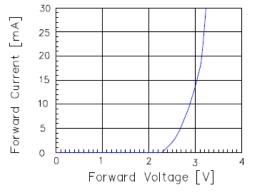
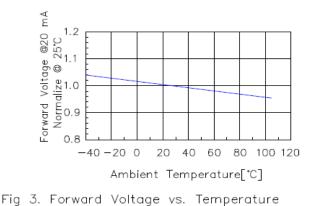
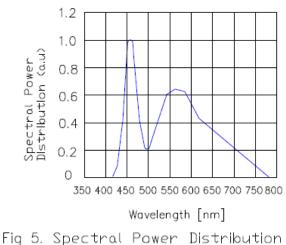
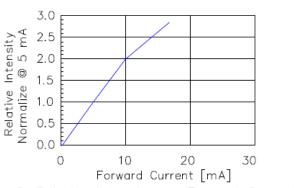


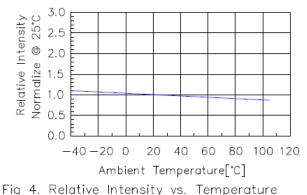
Fig 1. Forward Current vs. Forward Voltage

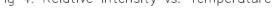












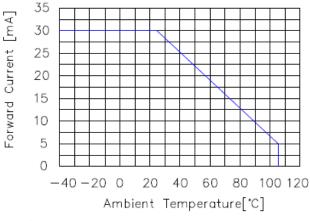
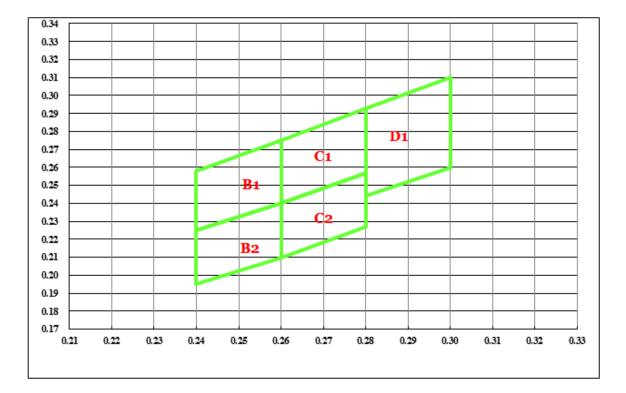


Fig 6. Forward current vs. Temperature

vs. Wavelength



Chromaticity Bin (for White only)



		B1		
Х	0.240	0.240	0.260	0.260
Y	0.225	0.258	0.275	0.240

		C1		
Х	0.260	0.260	0.280	0.280
Y	0.240	0.275	0.293	0.257

		B2		
Х	0.240	0.240	0.260	0.260
Y	0.195	0.225	0.240	0.210

		C2		
Х	0.260	0.260	0.280	0.280
Y	0.210	0.240	0.257	0.227

		D1		
Х	0.280	0.280	0.300	0.300
Y	0.244	0.293	0.310	0.260



Ordering Information

Product	Emission Color	Technology	I*V(mcd) @10mA	VF(V) @20mA	Polarity	Face Color	Orderable Part Number
					Common Anode	Black	INND-SS30YGAB
INND-SS30YGXX	Yellow Green	AlGaInP	2	2.0	Common Cathode	Black	INND-SS30YGCB
INND-33301 GAA	Tellow Green	AlGainF	2	2.0	Common Anode	Grey	INND-SS30YGAG
					Common Cathode	Grey	INND-SS30YGCG
					Common Anode	Black	INND-SS30YAB
INND-SS30YXX	Yellow	AlGaInP	8	2.0	Common Cathode	Black	INND-SS30YCB
	renow		0		Common Anode	Grey	INND-SS30YAG
					Common Cathode	Grey	INND-SS30YCG
					Common Anode	Black	INND-SS30AAB
	A rech e r				Common Cathode	Black	INND-SS30ACB
INND-SS30AXX	Amber	AlGaInP	9	2.0	Common Anode	Grey	INND-SS30AAG
					Common Cathode	Grey	INND-SS30ACG
					Common Anode	Black	INND-SS30RAB
					Common Cathode	Black	INND-SS30RCB
INND-SS30RXX	Red	AlGaInP	5	2.0	Common Anode	Grey	INND-SS30RAG
					Common Cathode	Grey	INND-SS30RCG

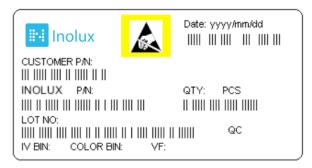


INND-SS30 Series 0.3" SMD Single Digit Display

Product	Emission Color	Technology I*V(mcd) @10mA		VF(V) @20mA	Polarity	Face Color	Orderable Part Number
					Common Anode	Black	INND-SS30DRAB
INND-SS30DRXX	Deep Red	AlGalnP	2	2.0	Common Cathode	Black	INND-SS30DRCB
INND-3330DRAA	Deep Red	AlGainr	2	2.0	Common Anode	Grey	INND-SS30DRAG
					Common Cathode	Grey	INND-SS30DRCG
					Common Anode	Black	INND-SS30GAB
INND-SS30GXX	Green	InGaN	37	3.2	Common Cathode	Black	INND-SS30GCB
INND-3330GAA					Common Anode	Grey	INND-SS30GAG
					Common Cathode	Grey	INND-SS30GCG
					Common Anode	Black	INND-SS30BAB
INND-SS30BXX	Blue				Common Cathode	Black	INND-SS30BCB
	Diue	InGaN	7	3.2	Common Anode	Grey	INND-SS30BAG
					Common Cathode	Grey	INND-SS30BCG
					Common Anode	Black	INND-SS30WAB
	White	InCoN	10.2	3.0	Common Cathode	Black	INND-SS30WCB
INND-SS30WXX	vvriite	InGaN	19.3	3.2	Common Anode	Grey	INND-SS30WAG
					Common Cathode	Grey	INND-SS30WCG



Label Specifications



Inolux P/N:

Ι	Ν	Ν	D	-	S	S	3	0	Х	Х	Х	-	х	х	Х	х
			olay pe		Display	у Туре	Dime	nsion	Color	Polarity	Face Color			ustor Stamp		
Inc	blux	Num) = neric olay		S: SME S: Si			0.30″ ' Height	YG: 570 nm Y: 590 nm A: 605 nm R: 630 nm DR: 660 nm G: 525 nm B: 465 nm W: X: 0.27 Y: 0.25	A = Common Anode C=Common Cathode	B = Black G = Grey					

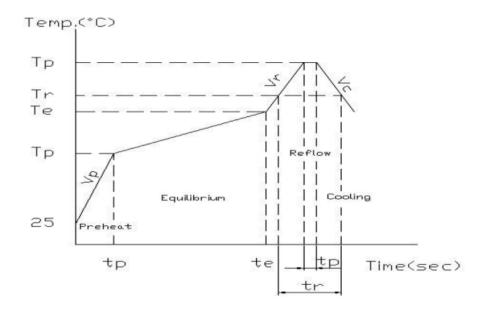
Lot No.:

Z	2	0	1	7	01	24	001
Internal		Year (2017	2019 \		Month	Date	Serial
Tracker		fear (2017)	, 2018,)	WOITT	Date	Sella	



Reflow Soldering

Area	Title	Symbol	Min	Max	Unit
	Ramp-up rate	Vp	1	5	°C/sec
(1)Preheat	temperature	Тр	150	_	C
	time	tp	_	_	sec
	Ramp-up rate	Ve	_	_	°C/sec
(2)Equilibrium	temperature	Те	150	200	C
	Time	te	60	120	sec
	Ramp-up rate	Vr	1	5	°C/sec
	temperature	Tr	220	_	C
(3)Reflow	Time	tr	_	60	sec
	Peak temperature	Тгр	_	260	C
	Peak time	trp	_	10	sec
(4)Cooling	Ramp-down rate	Vc	3	6	°C/sec



Soldering Iron

Basic Spec is ≤ 4 sec. when 260°C (+10°C \rightarrow -1 second). Power dissipation of Iron should be less than 15W. Surface temperature should be under 230°C

Rework

Rework should be completed within 4 second under 245°C



Revision History

Changes since last revision	Page	Version No.	Revision Date
Initial Release		1.0	07-12-2017
Information Revision	11	1.1	08-23-2022

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